

  	FQA8N80C_F109															
	<table><tr><td>Manufacturer Part Number:</td><td>FQA8N80C_F109</td></tr><tr><td>Manufacturer/Brand:</td><td>AMI Semiconductor / ON Semiconductor</td></tr><tr><td>Part of Description:</td><td>MOSFET N-CH 800V 8.4A TO-3P</td></tr><tr><td>Datasheets:</td><td> FQA8N80C_F109.pdf</td></tr><tr><td>RoHs Status:</td><td> Lead free / RoHS</td></tr><tr><td>Stock Condition:</td><td>Compliant New original, 2696 pcs Stock Available.</td></tr><tr><td>Ship From:</td><td>Hong Kong</td></tr><tr><td>Shipment Way:</td><td>DHL/Fedex/TNT/UPS/EMS</td></tr></table>	Manufacturer Part Number:	FQA8N80C_F109	Manufacturer/Brand:	AMI Semiconductor / ON Semiconductor	Part of Description:	MOSFET N-CH 800V 8.4A TO-3P	Datasheets:	 FQA8N80C_F109.pdf	RoHs Status:	 Lead free / RoHS	Stock Condition:	Compliant New original, 2696 pcs Stock Available.	Ship From:	Hong Kong	Shipment Way:
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Image may be representation. See specs for product details.																

Specifications

Part Number	FQA8N80C_F109
Manufacturer	AMI Semiconductor / ON Semiconductor
Description	MOSFET N-CH 800V 8.4A TO-3P
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2696 pcs Stock
Vgs(th) (Max) @ Id	5V @ 250μA
Vgs (Max)	±30V
Technology	MOSFET (Metal Oxide)
Supplier Device Package	TO-3PN
Series	QFET®
Rds On (Max) @ Id, Vgs	1.55 Ohm @ 4.2A, 10V
Power Dissipation (Max)	220W (Tc)
Packaging	Tube
Package / Case	TO-3P-3, SC-65-3
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Lead Free Status / RoHS Status	Lead free / RoHS Compliant
Input Capacitance (Ciss) (Max) @ Vds	2050pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	45nC @ 10V
FET Type	N-Channel
FET Feature	-
Drive Voltage (Max Rds On, Min Rds On)	10V
Drain to Source Voltage (Vdss)	800V
Detailed Description	N-Channel 800V 8.4A (Tc) 220W (Tc) Through Hole TO-
Current - Continuous Drain (Id) @ 25°C	8.4A (Tc)

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FQA8N80C_F109 Related keyword

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FQA8N80C_F109 Electronic	FQA8N80C_F109 Components	FQA8N80C_F109 Distributor	FQA8N80C_F109 Image
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